

Rad-hard plastic quad 2-input NAND gate



Features

- NAND gate
- 6 V max. operating
- 7 V max. rating
- · 8 ns propagation delay
- · Nickel/palladium/gold-lead-finished (NiPdAu), whisker-free
- · Gold-wires
- RML <1% and CVCM <0.1% guaranteed outgassing
- 50 krad (Si) total ionizing dose
- SEL-free up to 62.5 MeV.cm²/mg
- Mass: 80 mg
- Compliant with ST-LEO-specification

Application

Low earth orbit (LEO) applications

Description

The LEOAC00 is a CMOS low power quad 2-input NAND gate qualified for use in aerospace environments. It operates from 2 V to 6 V power supply (7 V absolute maximum ratings).

The LEOAC00 can operate over a large temperature range of -40 °C to +125 °C and it is housed in plastic TSSOP-20, thin-shrink small outline package, 20 leads, using gold-wires and nickel/palladium/golden-lead-finishing to prevent from whiskers.

The LEOAC00 is compliant with ST-LEO-specification, dedicated specification for space-ready rad-hard plastic products. This AEC-Q100-based specification offers a specific trade-off between footprint size savings, cost of ownership and quality assurance together with radiation hardness and large quantity capability.

Product status link

LEOAC00

1 Functional description

1A 1 20 VCC

1B 2 19 3A

1Y 3 18 3B

2A 4 17 3Y

2B 5 16 4A

2Y 6 15 4B

NC 7 14 4Y

NC 8 13 NC

Figure 1. Pin connections (top view)

NC: not internally connected.

NC 9

GND 10

The pin can be externally connected to any potential.

12 NC

11 NC

 Each gate

 INPUT (A)
 INPUT (B)
 OUTPUT (Y)

 L
 L
 H

 L
 H
 H

 H
 H
 H

 H
 H
 H

Table 1. Truth table

with: L = low level, H = high Level.

For all inputs, VIN = VIH minimum or VIL maximum, verify output VOUT.

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2 Maximum ratings and operating conditions

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-------------------------------|--|--------------------------------|------|
| VCC ⁽¹⁾ | Maximum power supply between VCC and GND | -0.5 to 7 | V |
| VIN | DC input voltage range | -0.5 to VCC+0.5 (and 7 V max.) | V |
| VOUT | DC output voltage range | -0.5 to VCC+0.5 (and 7 V max.) | V |
| IK | I/O clamp diode current | +/-20 | mA |
| T _{stg} | Maximum temperature storage | -65 to 150 | °C |
| T _j ⁽²⁾ | Maximum junction temperature | +150 | °C |
| Rth ⁽³⁾ | Junction-to-ambient thermal resistance (Θja) | 80 | °C/W |
| Runo | Junction-to-case thermal resistance (Θjc) | 17 | °C/W |
| ESD | HBM (human body model) | 2 k | V |
| LSD | CDM (charged device model) | 1 k | V |

- 1. All voltages, except differential I/O bus voltage, are with respect to the network ground terminal.
- 2. Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions as per the method 5004 of MIL-STD-883.
- 3. Short-circuits can cause excessive heating. Destructive dissipation can result from short-circuits on the amplifiers.

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All values are referred to GND.

Table 3. Operating conditions

| Symbol | Parameter | Min. | Max. | Unit |
|--------|---------------------------|------|------|------|
| VCC | Analog supply voltage | 2 | 6 | V |
| VIN | Input voltage range | 0 | VCC | V |
| VOUT | Output voltage range | 0 | VCC | V |
| Ta | Ambient temperature range | -40 | +125 | °C |

Note: All unused inputs must be held at VCC or GND to ensure proper device operation.

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3 Electrical characteristics

VCC = 3 V to 5.5 V, typical values are at ambient T_a = +25 °C, minimum and maximum values are at T_a = -40 °C and +125 °C, unless otherwise specified.

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | | Min. | Тур. | Max. | Unit | |
|--------------------|------------------------------|--|-------|------|------|------|------|--|
| | | For all inputs affecting output under test, VIN = VIH | 3 V | 2.9 | | | | |
| | | minimum or VIL maximum For all other inputs, | 4.5 V | 4.4 | | | | |
| | | VIN = VCC or GND, IOH = -50 μA | 5.5 V | 5.4 | | | | |
| VOH (1) | High level output voltage | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, VIN = VCC or GND, IOH = -12 mA | 3 V | 2.4 | | | V | |
| 7011 | . ng.n io roi output roitago | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, | 4.5 V | 3.7 | | | · | |
| | | VIN = VCC or GND, IOH = -24 mA | 5.5 V | 4.7 | | | | |
| | | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, VIN = VCC or GND IOH = -50 mA | 5.5 V | 3.85 | | | | |
| | | | 3 V | | | 0.1 | | |
| | | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, | 4.5 V | | | 0.1 | | |
| | | VIN = VCC or GND, IOL = +50 μA | 5.5 V | | | 0.1 | | |
| | | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, | 3 V | | | 0.5 | | |
| VOL ⁽¹⁾ | Low level output voltage | VIN = VCC or GND, IOL = +12 mA | | | | | V | |
| | | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, | 4.5 V | | | 0.5 | _ | |
| | | VIN = VCC or GND, IOL = +24 mA | 5.5 V | | | 0.5 | | |
| | | For all inputs affecting output under test, VIN = VIH minimum or VIL maximum. For all other inputs, VIN = VCC or GND, IOL = +50 mA | 5.5 V | | | 1.65 | | |
| | | VIIV - VOO OF GIVE, FOE - 130 HIM | 3 V | -12 | | | | |
| IOH | High level output current | | 4.5 V | -24 | | | | |
| | Transfer of the control of | | 5.5 V | -24 | | | | |
| | | | 3 V | | | 12 | mA | |
| IOL | Low level output current | | 4.5 V | | | 24 | | |
| | | | 5.5 V | | | 24 | | |
| | | | 3 V | 2.1 | | | | |
| VIH | VIH High level input voltage | | 4.5 V | 3.15 | | | | |
| | | | 5.5 V | 3.85 | | | ., | |
| | | | 3 V | | | 0.9 | V | |
| VIL | Low level input voltage | | 4.5 V | | | 1.35 | | |
| | | | 5.5 V | | | 1.65 | - | |
| VIC+ | Positive input clamp voltage | For input under test, IIN = 1 mA | 0 V | 0.4 | | 1.5 | V | |

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| Symbol | Parameter | Test conditions | VCC | Min. | Тур. | Max. | Unit |
|---------------------------------|---------------------------------------|--|-------|------|------|------|------|
| VIC- | Negative input clamp voltage | For input under test, IIN = -1.0 mA | Open | -0.4 | | -1.5 | V |
| IIH | Input current high | For input under test, VIN = VCC For all other inputs, VIN = VCC or GND | 5.5 V | | | 1 | μА |
| IIL | Input current low | For input under test, VIN = GND For all other inputs, VIN = VCC or GND | 5.5 V | | | -1 | μA |
| ICCH | Quiescent supply current, output high | For all inputs, VIN = VCC or GND IOUT = 0 A | 5.5 V | | | 40 | μA |
| ICCL | Quiescent supply current, output low | For all inputs, VIN = VCC or GND IOUT = 0 A | 5.5 V | | | 40 | μA |
| CIN ⁽²⁾ | Input capacitance | Ta=+25°C | 5 V | | | 10 | pF |
| CPD ⁽²⁾⁽³⁾ | Power dissipation capacitance | Ta=+25°C, F = 1 MHz | 5 V | | | 50 | pF |
| | | CL = 2 pF, RL = 500 ohm, | 3 V | | 3.3 | | |
| T_r , T_f | Output rise time and fall | see Figure 2. Waveform | 4.5 | | 2.7 | | ns |
| 10.11 | time | CL = 2 pF, RL = 500 ohm, | 3 V | | 4.6 | | 113 |
| | | see Figure 2. Waveform | 4.5 V | | 3.3 | | |
| t _{PHL} ⁽⁴⁾ | Propagation delay time | CL = 50 pF, RL = 500 ohm | 3 V | 1 | | 9.5 | |
| YPHL' | An to Yn, high to low | See Figure 2. Waveform | 4.5 V | 1 | | 8 | ns |
| t _{PLH} ⁽⁴⁾ | Propagation delay time | CL = 50 pF, RL = 500 ohm | 3 V | 1 | | 9.5 | 113 |
| 'PLH' | An to Yn, low to high | See Figure 2. Waveform | 4.5 V | 1 | | 8 | |

- 1. The VOH and VOL tests shall be tested at VCC = 3.0 V and 4.5 V. The VOH and VOL tests are guaranteed, if not tested, for other values of VCC. Limits shown apply to operation at VCC = 3.3 V ±0.3 V and VCC = 5.0 V ±0.5 V. Tests with input current at +50 mA and -50 mA are performed on only one input at a time with duration not to exceed 10 ms. Transmission driving tests may be performed using VIN = VCC or GND. When VIN = VCC or GND is used, the test is guaranteed for VIN = VIH minimum and VIL maximum.
- 2. CIN and CPD shall be measured only for initial qualification and after process or design changes which may affect capacitance. CIN shall be measured between the designated terminal and GND at a frequency of 1 MHz. CPD shall be tested in accordance with the latest revision of JEDEC standard JESD20 and table IA herein. For CIN and CPD, test all applicable pins on five devices with zero failures.
- 3. Power dissipation capacitance (CPD) determines both the power consumption (PD) and dynamic current consumption (IS). Where: PD = (CPD + CL) (VCC x VCC) f + (ICC x VCC) and IS = (CPD + CL) VCC x f + ICC, and f is the frequency of the input signal and CL is the external output load capacitance.
- 4. The AC limits at VCC = 5.5 V are equal to the limits at VCC = 4.5 V and guaranteed by testing at VCC = 4.5 V. The AC limits at VCC = 3.6 V are equal to the limits at VCC = 3.0 V and guaranteed by testing at VCC = 3.0 V. Minimum AC limits for VCC = 5.5 V and VCC = 3.6 V are 1.0 ns and guaranteed by guard banding the VCC = 4.5 V and VCC = 3.0 V minimum limits, respectively, to 1.5 ns. For propagation delay tests, all paths must be tested.

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Waveform and test circuit

Figure 2. Waveform

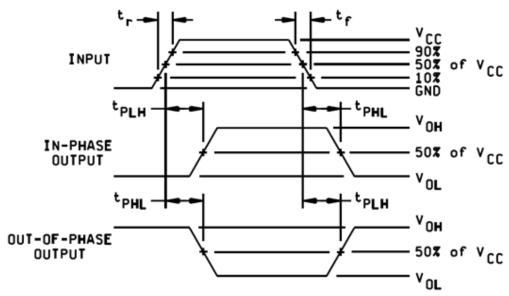
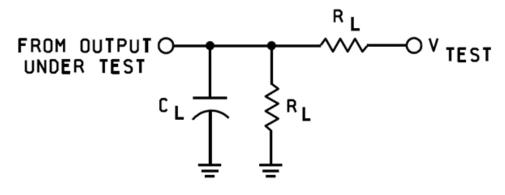


Figure 3. Test circuit



Note:

- When measuring t_{PHL} or t_{PLH} : VTEST = open.
- CL = 50 pF minimum or equivalent (includes probe and jig capacitance).
- $RL = 500 \Omega$ or equivalent.
- Input signal from pulse generator: VIN = 0.0 V to VCC; PRR \leq 1 MHz; ZO = 50 Ω ; tr \leq 3.0 ns; tf \leq 3.0 ns; t_r and t_f shall be measured from 10% of VCC to 90% of VCC and from 90% of VCC to 10% of VCC, respectively; duty cycle = 50 percent.
- Timing parameters shall be tested at a minimum input frequency of 1 MHz.
- The outputs are measured one at a time with one transition per measurement.

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5 Radiations

Total ionizing dose (TID):

For the qualification, the product is characterized in TID as per MIL-STD-883 TM 1019 up to 50 krad (Si) on 5 biased parts at high dose rate, such a rate being the worst condition for a pure CMOS technology.

All parameters provided in Table 4. Electrical characteristics apply to both pre- and post-irradiation.

Each new production lot is tested at high dose rate as per MIL-STD-883 TM 1019 on 5 parts.

Heavy-ions

Single event latchup (SEL) is characterized at 125 $^{\circ}$ C at a LET of 62.5 MeV.cm2/mg. The test shows the product is immune to heavy ions at this LET. Heavy-ion trials are performed on qualification lots only.

The results in radiation are summarized in Table 5 as follows:

Table 5. Radiations

| Symbol | Characteristics | Value |
|--------|--|---|
| TID | High-dose rate (40 krad (Si) / h) Temperature: 25 °C Performed on 5 biased parts | Within Table 4 up to 50 krad (Si) |
| SEL | LET: 62.5 MeV.cm2/mg (Xenon ions) Temperature: 125 °C Fluence: 1 x 10⁷ ions/cm² (10 million of particles per cm²) Normal incidence | Immune to SEL up to 62.5 MeV.cm ² /mg |

^{1.} A total ionizing dose (TID) of 50 krad(Si) is equivalent to 500 Gy(Si), (1 gray = 100 rad).

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^{2.} SEL: single event latch-up.



6 Outgassing

| Specification (tested per ASTM E 595) | Value | Unit |
|---|-------|------|
| Recovered mass loss (RML) ⁽¹⁾ | 0.06 | % |
| Collected volatile condensable material (CVCM) ⁽²⁾ | 0.00 | % |

^{1.} RML < 1%.

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^{2.} CVCM < 0.1%.



7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

7.1 TSSOP-20 package information

Figure 4. TSSOP-20 package outline

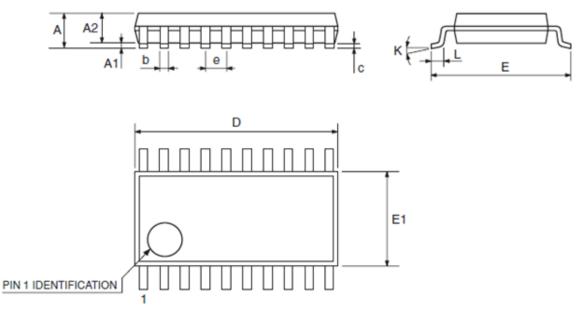


Table 6. TSSOP-20 package mechanical data

| Symbol | | Milimeters | | Inches ⁽¹⁾ | | |
|--------|------|------------|------|-----------------------|------------|-------|
| Symbol | Min. | Тур. | Max. | Min. | Тур. | Max. |
| Α | | | 1.2 | | | 0.047 |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | | 0.30 | 0.007 | | |
| С | 0.09 | | 0.20 | 0.004 | | |
| D | 6.4 | 6.5 | 6.6 | 0.252 | 0.256 | 0.260 |
| Е | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 |
| е | | 0.65 BSC | | | 0.0256 BSC | |
| К | 0° | | 8° | 0° | | 8° |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |

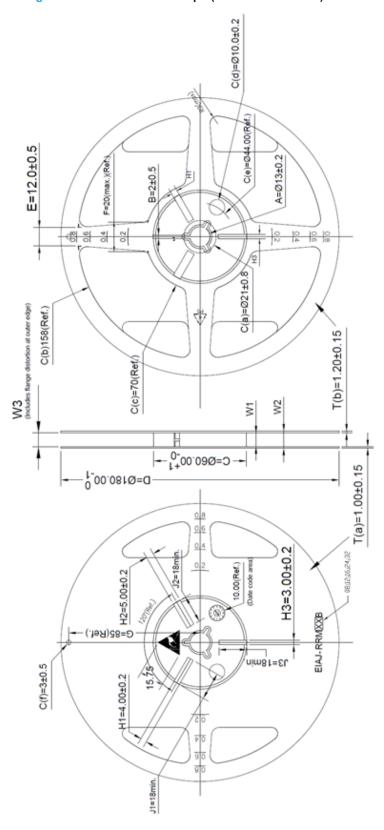
^{1.} Values in inches are converted from mm and rounded to 4 decimal digits.

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7.2 TSSOP-20 packing information

Figure 5. TSSOP-20 Carrier tape (dimensions in mm) outline



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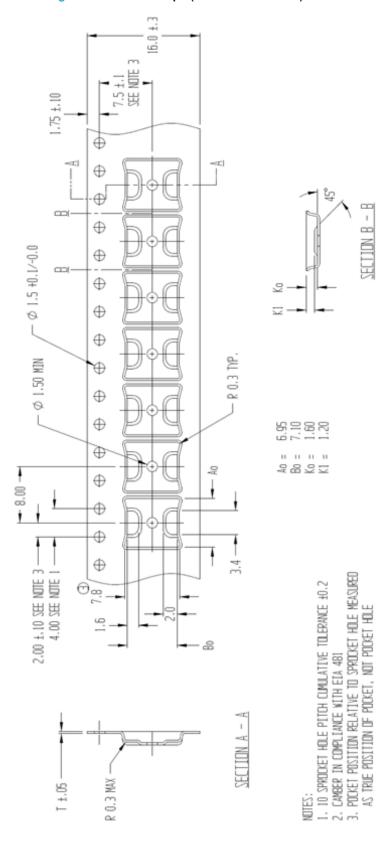


Figure 6. TSSOP-20 tape (dimensions in mm) outline

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8 Ordering information

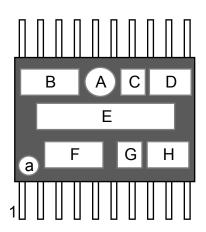
Table 7. Ordering information

| Order code | Quality level | Package | Lead-finish | Marking | Packing |
|-------------|--------------------|----------|-------------|----------|---------------|
| LEOAC00PT-D | Development sample | TSSOP-20 | NiPdAu | DLEOAC00 | Tape and reel |
| LEOAC00PT | Flight model | TSSOP-20 | NiPdAu | LEOAC00 | Tape and reel |

Table 8. Order code

| LEO | AC00 | Р | Т |
|-------------------|------|------------------|---------------|
| LEO qualification | Name | TSSOP-20 package | Tape and reel |

Figure 7. TSSOP-20 marking



- a: pin-1 reference
- A: Second Level of interconnexion (type of lead-finishing)
- B: ST logo
- C: Assy plant
- D: Lot code
- E: Marking area
- F: Country of origin
- G: Assy year
- H: Assy week

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Revision history

Table 9. Document revision history

| Date | Version | Changes |
|-------------|---------|---|
| 10-Feb-2021 | 1 | Initial release. |
| 29-Mar-2021 | 2 | Updated Section 8 Ordering information. Removed "product documentation" section. |
| 08-Jun-2021 | 3 | Updated T _{STG} value in Table 2 and TID characteristics in Table 5. |
| 30-Aug-2021 | 4 | Updated Section 5 Radiations. |

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